

TOSHIBA Photocoupler GaAs Ired & Photo-Triac

TLP360J

Triac Drivers

Programmable Controllers

AC-Output Modules

Solid State Relays

The TOSHIBA TLP360J consists of a photo-triac optically coupled to a gallium arsenide infrared-emitting diode in a four-lead plastic DIP package.

- Peak off-state voltage: 600 V (Min.)
- Trigger LED current: 10 mA (Max.)
- On-state current: 100 mA (Max.)
- Isolation voltage: 5000 Vrms (Max.)
- UL recognized: UL1577, file No. E67349
- Option (D4) type
TÜV approved: DIN EN60747-5-2

Certificate No. R50033433

Maximum operating insulation voltage : 890 Vpk

Maximum permissible overvoltage : 8000 Vpk

(Note) When an EN60747-5-2 approved type is needed, please designate "Option (D4)."

- Construction mechanical rating

	7.62 mm pitch standard type	10.16 mm pitch TLPXXXF type
Creepage distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation thickness	0.4 mm (min)	0.4 mm (min)

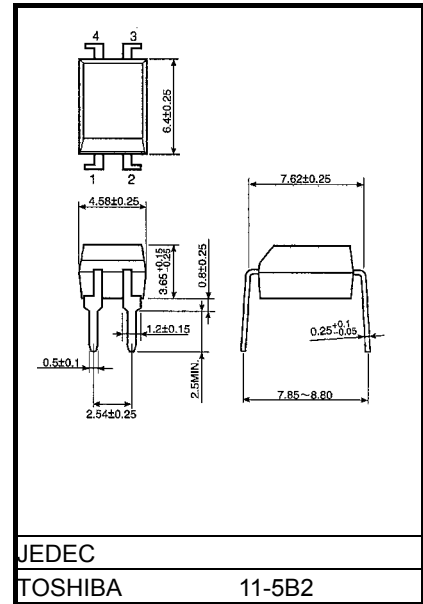
- Trigger LED Current

Classi- fication*	Trigger LED current (mA)		Marking of classification
	V _T = 6 V, Ta = 25°C		
	Min.	Max.	
(IFT7)	—	7	T7
Standard	—	10	T7, blank

*Example: "(IFT7)"; "TLP360J(IFT7)"

(Note) When specifying the application type name for certification testing, be sure to use the standard product type name, e.g., TLP360J(IFT7): TLP360J.

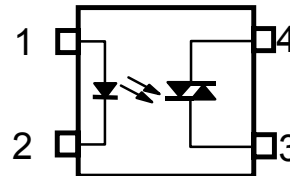
Unit: mm



JEDEC
TOSHIBA 11-5B2

Weight: 0.26 g (Typ.)

Pin configuration (top view)



- 1: Anode
- 2: Cathode
- 3: Terminal1
- 4: Terminal2

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≥ 53°C)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / °C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{DRM}	600	V
	On-state RMS current	Ta = 25°C	100	mA
		Ta = 70°C	50	
	On-state current derating (Ta ≥ 25°C)	$\Delta I_T / ^\circ\text{C}$	-1.1	mA / °C
	Peak on-state current (100 μs pulse, 120 pps)	I_{TP}	2	A
	Peak nonrepetitive surge current (Pw = 10 ms, DC = 10%)	I_{TSM}	1.2	A
	Junction temperature	T_j	115	°C
Storage temperature range	T_{stg}	-55~125	°C	
Operating temperature range	T_{opr}	-40~100	°C	
Lead soldering temperature (10 s)	T_{sol}	260	°C	
Isolation voltage (AC, 1 min., R.H. ≤ 60%)	(Note 1) BV_S	5000	Vrms	

(Note 1): Pins 1 and 2 are shorted together and pins 3 and 4 are shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{AC}	—	—	240	V_{ac}
Forward current	I_F	15	20	25	mA
Peak on-state current	I_{TP}	—	—	1	A
Operating temperature	T_{opr}	-25	—	85	°C

Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Peak off-state current	I_{DRM}	$V_{DRM} = 600 \text{ V}$	—	10	1000	nA
	Peak on-state voltage	V_{TM}	$I_{TM} = 100 \text{ mA}$	—	1.7	3.0	V
	Holding current	I_H	—	—	0.6	—	mA
	Critical rate of rise of off-state voltage	dv/dt	$V_{in} = 240 \text{ Vrms}, T_a = 85^\circ\text{C}$ (Note 2)	—	500	—	V/ μs
	Critical rate of rise of commutating voltage	dv/dt(c)	$V_{in} = 60 \text{ Vrms}, I_T = 15 \text{ mA}$ (Note 2)	—	0.2	—	V/ μs

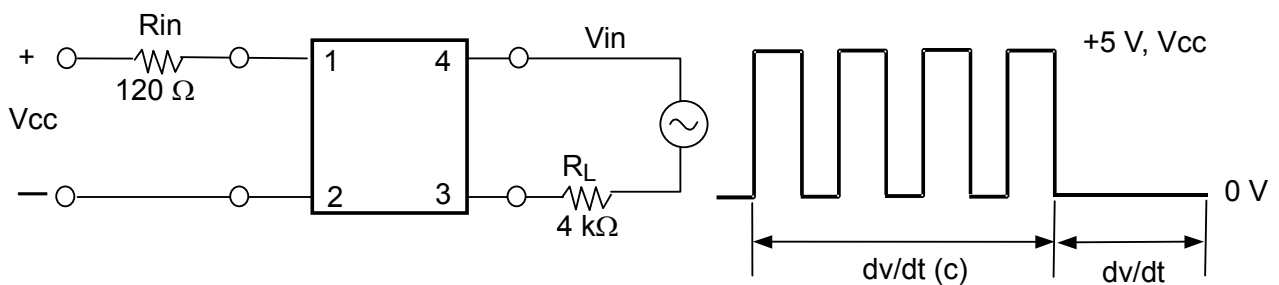
Coupled Electrical Characteristics (Ta = 25°C)

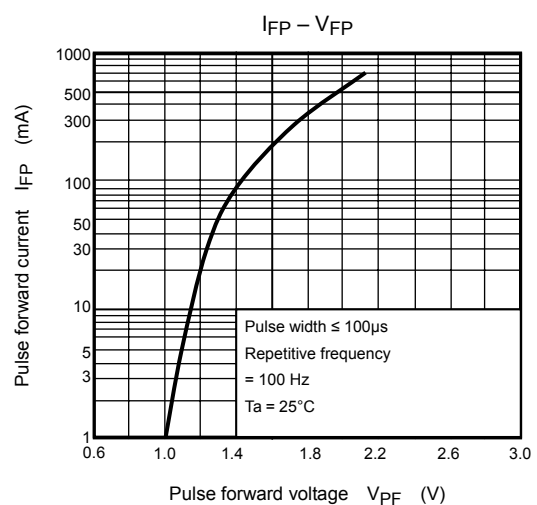
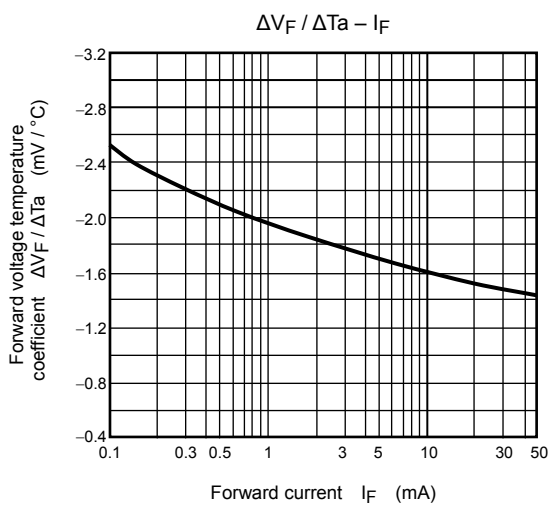
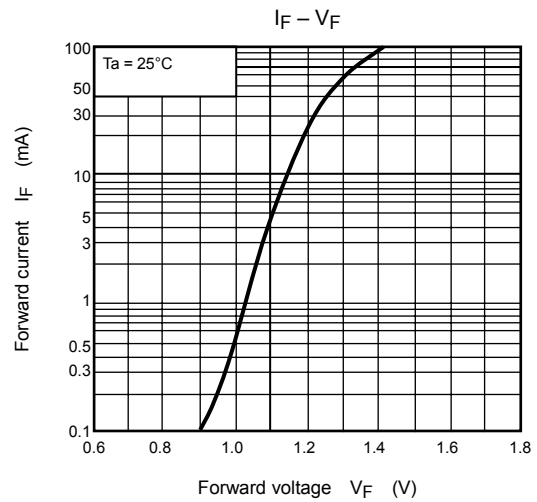
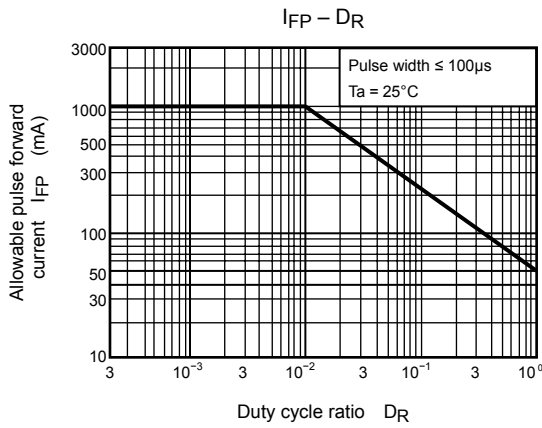
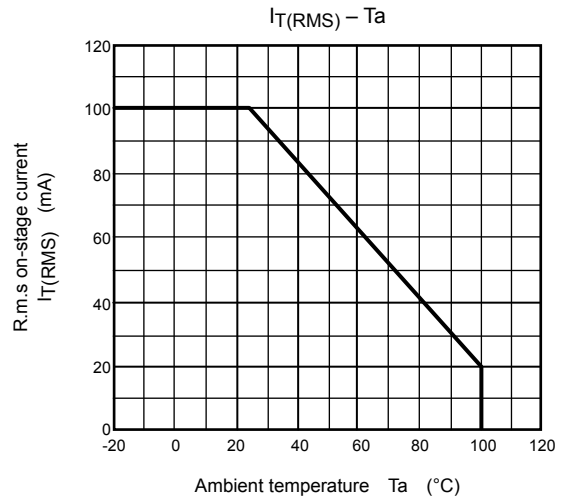
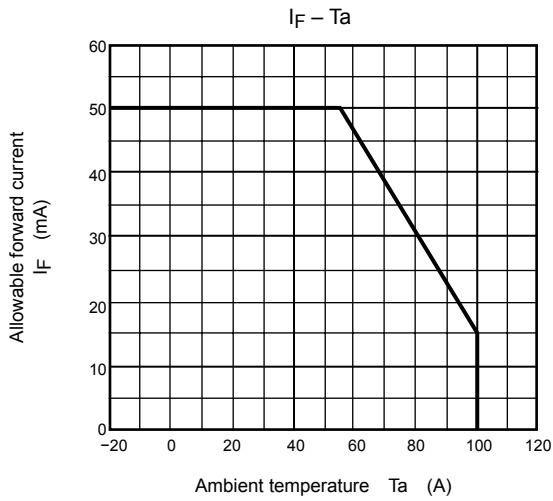
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	I_{FT}	$V_T = 6 \text{ V}$	—	—	10	mA
Turn-on time	t_{ON}	$V_D = 6 \rightarrow 4 \text{ V}, R_L = 100 \Omega$ $I_F = \text{Rated } I_{FT} \times 1.5$	—	30	100	μs

Isolation Characteristics (Ta = 25°C)

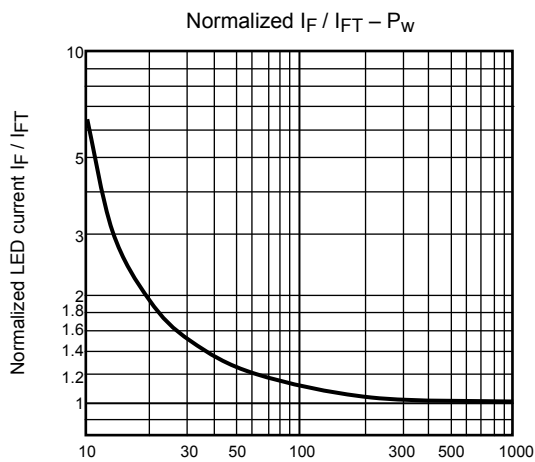
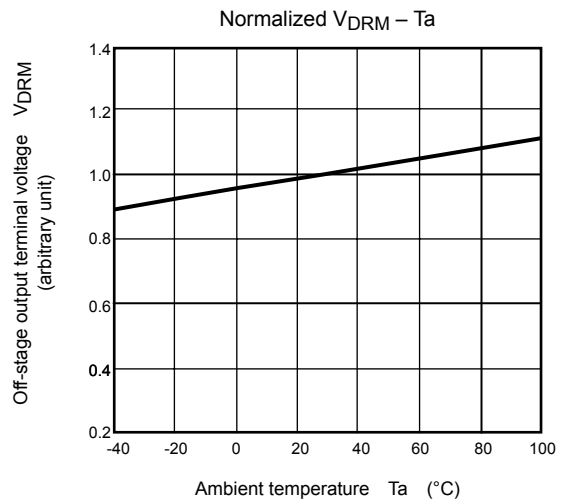
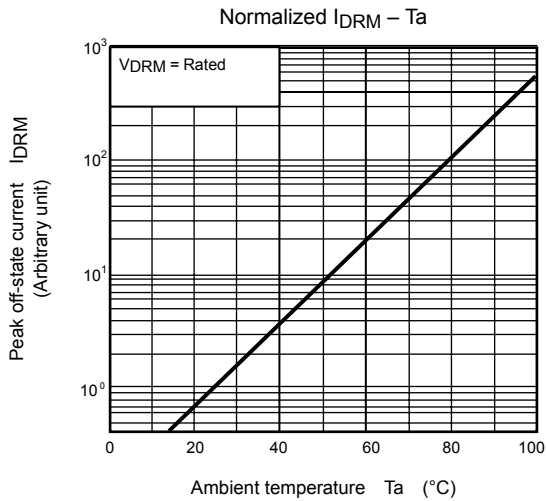
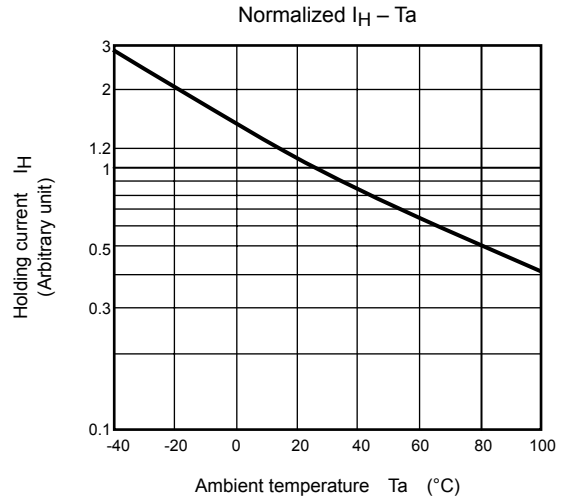
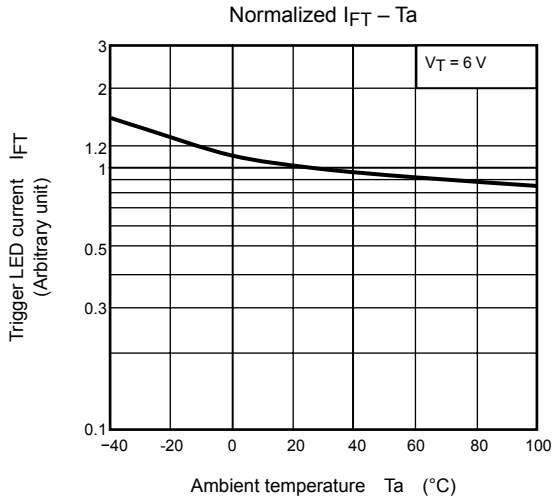
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance (input to output)	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	1×10^{12}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	5000	—	—	Vrms
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

(Note 2): dv/dt test circuit





*: The above graphs show typical characteristics.



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GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human bo